PNP Current Driver Transistor

NZT753

This device is designed for power amplifier, regulator and switching circuits where speed is important. Sourced from Process 5P.

ABSOLUTE MAXIMUM RATINGS

 $(T_A = 25^{\circ}C \text{ unless otherwise noted.})$ (Notes 1, 2)

Symbol	Parameter	Value	Unit
V _{CEO}	Collector-Emitter Voltage	-100	V
V _{CBO}	Collector-Base Voltage	-120	V
V _{EBO}	Emitter-Base Voltage	-5.0	V
Ι _C	Collector Current – Continuous	-4.0	А
T _J , T _{STG}	Operating and Storage Junction Temperature Range	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. These ratings are based on a maximum junction temperature of 150°C.

These are steady limits. The factory should be consulted on application involving pulsed or low duty cycle operations.

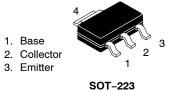
THERMAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted.) (Note 3)

Symbol	Parameter	Max	Unit
P _D	Total Device Dissipation Derate above 25°C	1.2 9.7	W mW/°C
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	103	°C/W

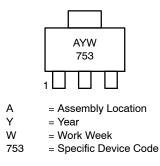
 Device mounted on FR-4PCB 36 mm × 18 mm × 1.5 mm; mounting pad for the collector lead min. 6 cm².

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted.) (Note 4)



CASE 318H

MARKING DIAGRAM



ORDERING INFORMATION

Device	ce Package Shippir	
NZT753	SOT-223 (Pb-Free)	4,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Symbol	Parameter	Test Conditions	Min	Max	Unit
OFF CHAF	ACTERISTICS				
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = -10$ mA, $I_{\rm B} = 0$	-100	-	V
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{C} = -100 \ \mu A, \ I_{E} = 0$	-120	-	V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_{E} = -100 \ \mu A, \ I_{C} = 0$	-5.0	-	V
I _{CBO}	Collector-Base Cutoff Current	$V_{CB} = -100 \text{ V}, \text{ I}_{E} = 0$ $V_{CB} = -100 \text{ V}, \text{ I}_{E} = 0, \text{ T}_{A} = 100^{\circ}\text{C}$	-	-0.1 -10	μΑ μΑ
I _{EBO}	Emitter-Base Cutoff Current	$V_{EB} = -4 \text{ V}, \text{ I}_{C} = 0$	-	-0.1	μA
ON CHAR	ACTERISTICS (Note 4)				
h _{FE}	DC Current Gain	$ \begin{array}{l} V_{CE} = -2.0 \text{ V}, \ I_{C} = -50 \text{ mA} \\ V_{CE} = -2.0 \text{ V}, \ I_{C} = -500 \text{ mA} \\ V_{CE} = -2.0 \text{ V}, \ I_{C} = -1.0 \text{ A} \end{array} $	70 100 55	 300 	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = -1.0 A, I _C = -50 mA		-0.3	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C = -1.0 A, I _B = -100 mA		-1.25	V

NZT753

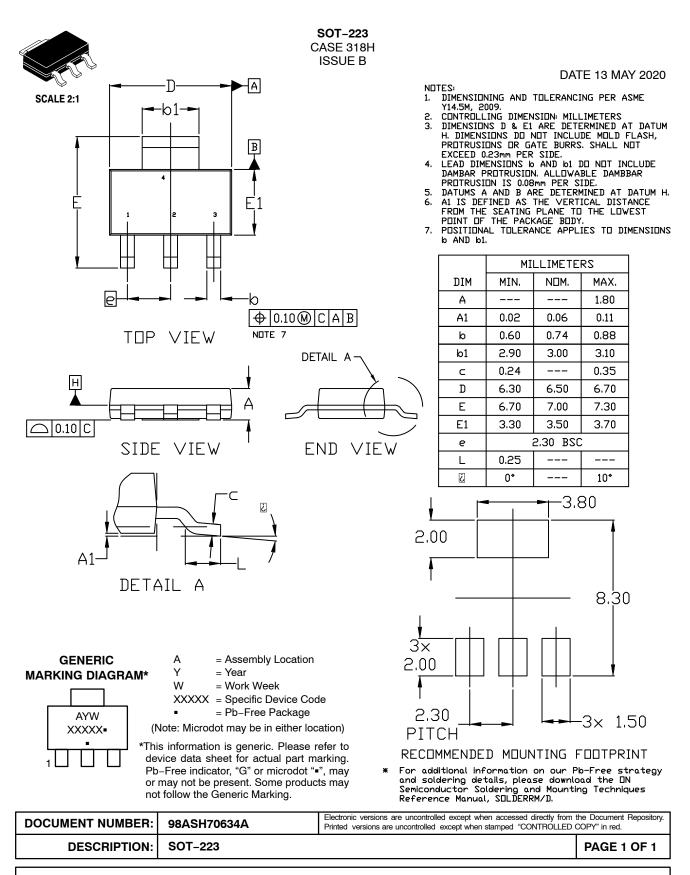
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted.) (Note 4) (continued)

Symbol	Parameter	Test Conditions	Min	Max	Unit
ON CHARACTERISTICS (Note 4)					
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = -2.0 \text{ V}, \text{ I}_{C} = -1.0 \text{ A}$	-	-1.0	V
SMALL SIGNAL CHARACTERISTICS					
f _T	Transition Frequency	$V_{CE} = -5 \text{ V}, \text{ I}_{C} = -100 \text{ mA}, \text{ f} = 100 \text{ MHz}$	75	_	MHz

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

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PACKAGE DIMENSIONS



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